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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Gurtej S. Sandhu et al.

Examiner: Laura M Schillinger

Patent No.: 7,344,948.

Group Art Unit: 2813

Issue Date: March 18, 2008

Docket No: 1999-0914.02/US

Title: METHODS OF FORMING TRANSISTORS

Commissioner for Patents
Office of Patent Publication
ATTN: Certificate of Correction Branch

Certificate
APR 02 2008
of Correction

We are transmitting herewith the attached:

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- ☒ Certificate of Correction Form - PTO-1050 (in duplicate)
- ☒ A return postcard.


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Customer Number: 26809

Respectfully submitted,

Date: March 28, 2008

By: _____


Russ Slifer
Reg. No. 39,838

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Christine Hartness

Name



Signature

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IN UNITED STATES PATENT AND TRADEMARK OFFICE

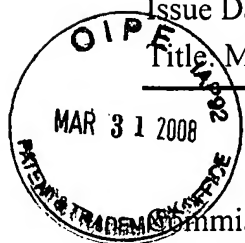
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REQUEST FOR CERTIFICATION OF CORRECTION

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Alexandria, VA 22313-1450
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It is requested that a Certificate of Correction be issued correcting printing errors appearing in the above-identified United States patent. Two copies of the text of the Certificate in the suggested form are enclosed.

As the error is that of the Patent Office, it is believed that no fee is due.

Issuance of the Certificate of Correction would neither expand nor contract the scope of the claims as properly allowed, and re-examination is not required.

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 7,344,948

Page (1) of 1

DATED : March 18, 2008

INVENTOR(S) : Sandhu et al.

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the face page, in field (62), under "Related U.S. Application Data", in column 1, line 2, delete "2000." and insert - - 2000, now U.S. Patent No. 6,660,657. - -, therefor.

In column 1, line 7, delete "2000." and insert - - 2000, now U.S. Patent No. 6,660,657. - -, therefor.

In column 5, line 27, in Claim 1, after "upper" insert - - oxide-comprising - -.

In column 5, line 28, in Claim 1, after "lower" insert - - oxide-comprising - -.

In column 5, line 36, in Claim 1, delete "400°" and insert - - 400° C. - -, therefor.

In column 5, line 37, in Claim 1, delete "exposing,thermally" and insert - - exposing, thermally - -, therefor.

In column 6, line 3, in Claim 1, delete "silicon-oxide-containing" and insert - - gate oxide - -, therefor.

In column 6, line 5, in Claim 1, delete "at least one" and insert - - a - -, therefor.

In column 6, line 5, in Claim 1, delete "over" and insert - - on and in direct physical contact with the upper oxide-comprising surface of - -, therefor.

In column 6, line 19, in Claim 4, delete "500watts" and insert - - 500 watts - -, therefor.

In column 6, lines 26-27, in Claim 7, delete "The method of claim 1 wherein the exposing occurs for a time of less than or equal to about 1 minute." and
insert - - The method of claim 1 wherein the annealing comprises thermal processing at temperature of less than 1100° C. for a time of at least 3 seconds. - -, therefor.

In column 6, line 28, in Claim 8, after "is" insert - - a - -.

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